

# IR-Lumineszenzdiode (880 nm) im TO-46-Gehäuse Infrared Emitter (880 nm) in TO-46 Package

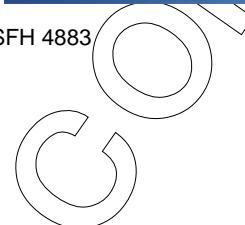
**SFH 4881**  
**SFH 4883**



SFH 4881



SFH 4883



## Wesentliche Merkmale

- Hergestellt im Schmelzepitaxieverfahren
- Anode galvanisch mit dem Gehäuseboden verbunden
- Hohe Zuverlässigkeit
- Gute spektrale Anpassung an Si-Fotoempfänger
- Hermetisch dichtes Metallgehäuse

## Anwendungen

- Lichtschranken für Gleich- und Wechsellichtbetrieb
- IR-Gerätefernsteuerungen
- Sensorik

## Features

- Fabricated in a liquid phase epitaxy process
- Anode is electrically connected to the case
- High reliability
- Matches all Si-Photodetectors
- Hermetically sealed package

## Applications

- Photointerrupters
- IR remote control of various equipment
- Sensor technology
- Light-grille barrier

Typ Type	Bestellnummer Ordering Code	Gehäuse Package
SFH 4881	Q62702-P5302	TO-46-Metallgehäuse, Glaslinse, hermetisch dicht, Anschlüsse im 2.54-mm-Raster ( $\frac{1}{10}$ ')
SFH 4883	Q62702-P5303	TO-46-metal-package, glass lens, hermetically sealed, solder tabs lead spacing 2.54 mm ( $\frac{1}{10}$ ')

**Grenzwerte ( $T_A = 25^\circ\text{C}$ )****Maximum Ratings**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}; T_{\text{stg}}$	-40 ... +100	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Durchlaßstrom Forward current	$I_F$	200	mA
Stoßstrom Surge current $t_p = 10 \mu\text{s}, D = 0.01$	$I_{\text{FSM}}$	2.5	A
Verlustleistung Power dissipation	$P_{\text{tot}}$	470	mW
Wärmewiderstand Thermal resistance	$R_{\text{thJA}}$ $R_{\text{thJC}}$	450 160	K/W K/W

**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Wellenlänge der Strahlung Wavelength of peak emission	$\lambda_{\text{peak}}$	880	nm
Spektrale Bandbreite bei 50% von $I_{\text{max}}$ Spectral bandwidth at 50% of $I_{\text{max}}$	$\Delta\lambda$	80	nm
Abstrahlwinkel Half angle SFH 4881 SFH 4883	$\phi$ $\phi$	$\pm 5$ $\pm 35$	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.16	mm <sup>2</sup>
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	0.4 × 0.4	mm

Kennwerte ( $T_A = 25^\circ\text{C}$ ) (cont'd)

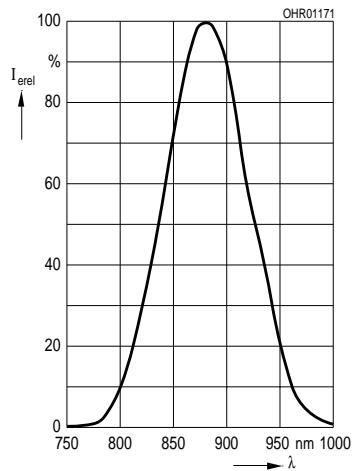
## Characteristics

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10% Switching times, $I_e$ from 10% to 90% and from 90% to 10% $I_F = 100 \text{ mA}, R_L = 50 \Omega$	$t_r, t_f$	500	ns
Kapazität Capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_o$	25	pF
Durchlaßspannung Forward voltage $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$ $I_F = 1.5 \text{ A}, t_p = 100 \mu\text{s}$	$V_F$ $V_F$ $V_F$	1.5 ( $\leq 1.8$ ) 2.4 ( $\leq 3.0$ ) 2.9 ( $\leq 3.4$ )	V
Sperrstrom Reverse current $V_R = 5 \text{ V}$	$I_R$	0.01 ( $\leq 10$ )	$\mu\text{A}$
Gesamtstrahlungsfluß Total radiant flux $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ SFH 4881 SFH 4883	$\Phi_e$ $\Phi_e$	12 15	mW mW

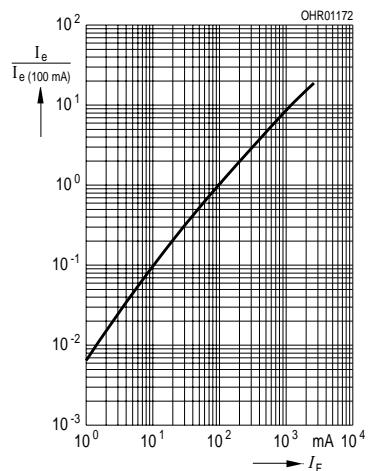
Strahlstärke  $I_e$  in Achsrichtunggemessen bei einem Raumwinkel von  $\Omega = 0.01 \text{ sr}$ Radiant Intensity  $I_e$  in Axial Directionmeasured at a solid angle of  $\Omega = 0.01 \text{ sr}$ 

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		SFH 4881	SFH 4883	
Strahlstärke Radiant intensity $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$I_{e \min}$ $I_{e \text{ typ}}$	40 72	4 8	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$I_{e \text{ typ}}$	630	70	mW/sr

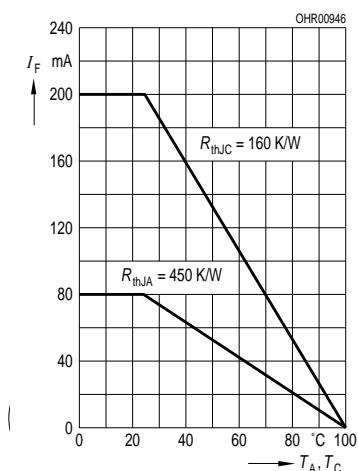
**Relative Spectral Emission**  
 $I_{\text{erel}} = f(\lambda)$



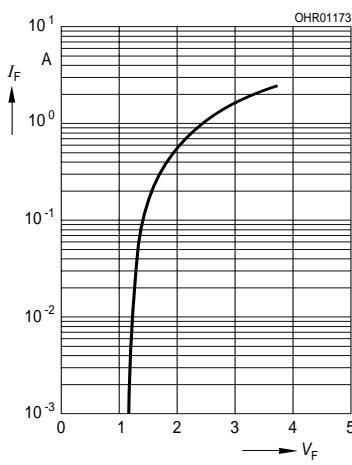
**Radiant Intensity**  
 $I_e/I_{e(100 \text{ mA})} = f(I_F)$



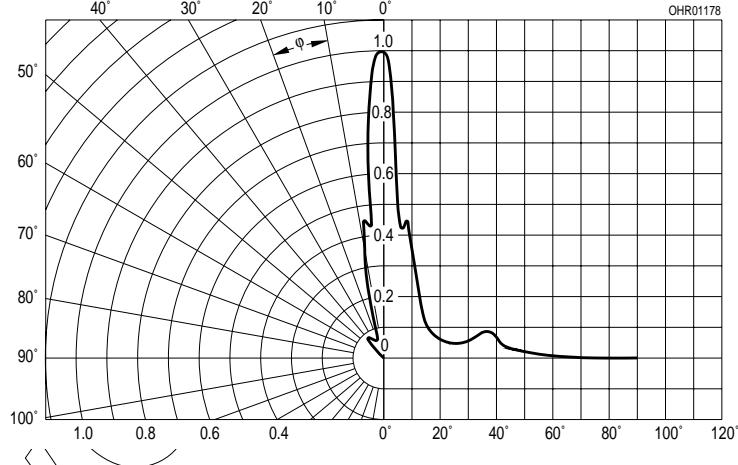
**Max. Permissible Forward Current**  
 $I_F = f(T_A, T_C)$



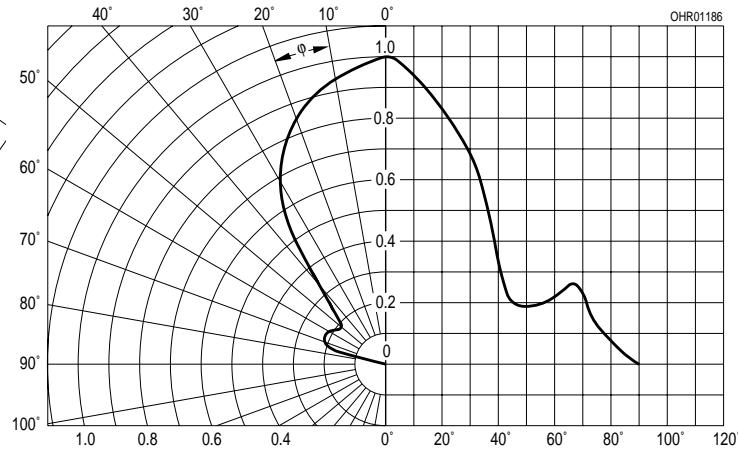
**Forward Current**  
 $I_F = f(V_F)$



**Radiation Characteristic**  
SFH 4881,  $I_{\text{erel}} = f(\phi)$

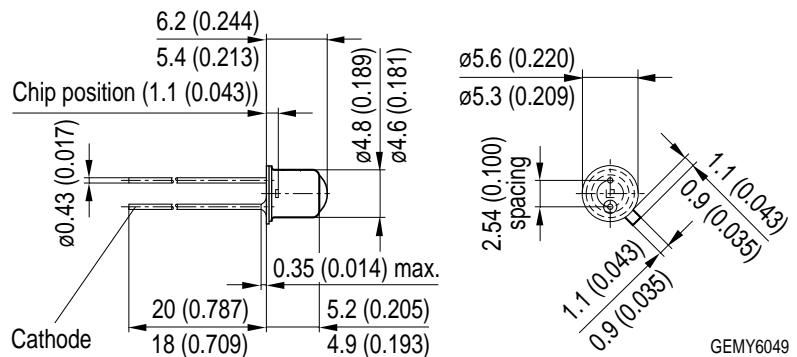


**Radiation Characteristic**  
SFH 4883,  $I_{\text{erel}} = f(\phi)$



**Maßzeichnungen**  
**Package Outlines**

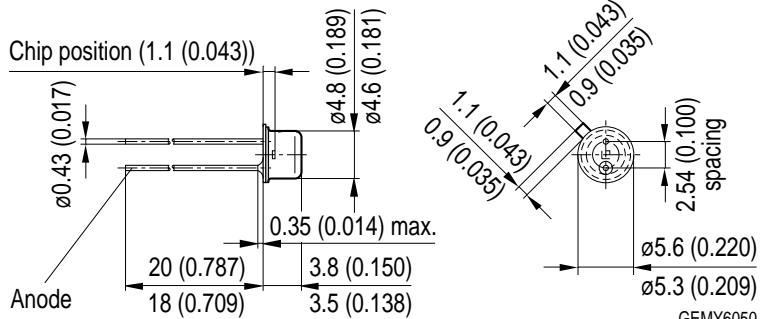
SFH 4881



μm

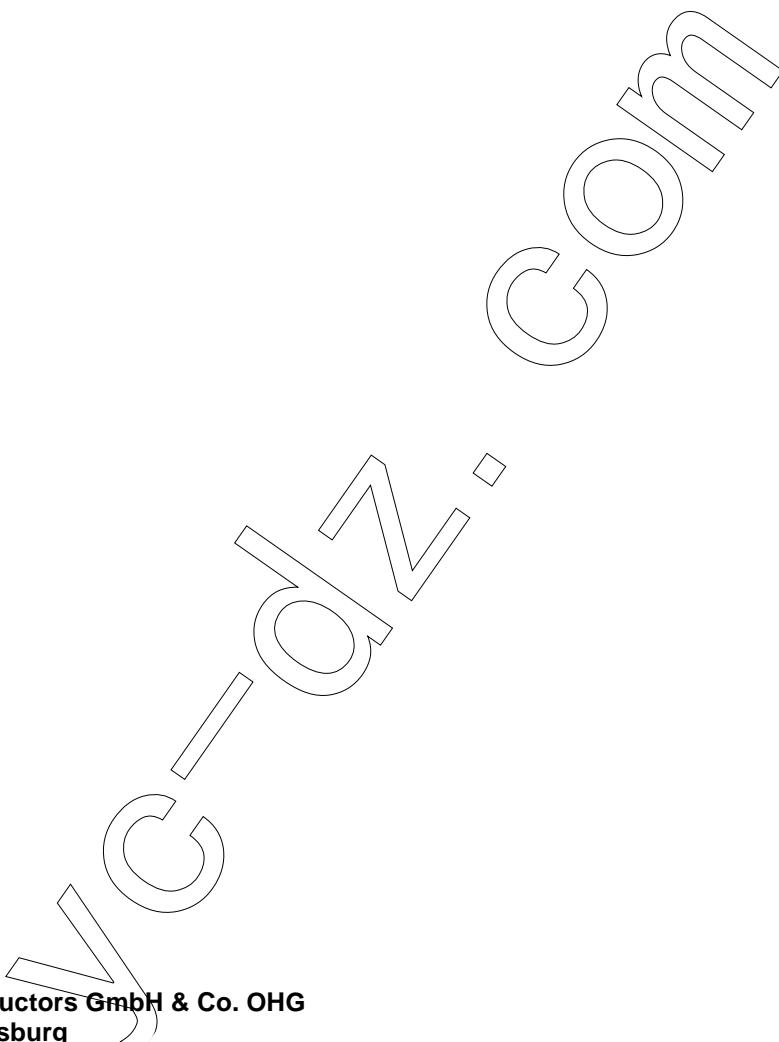
GEMY6049

SFH 4883



GEMY6050

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).



Published by OSRAM Opto Semiconductors GmbH & Co. OHG  
Wernerwerkstrasse 2, D-93049 Regensburg

© All Rights Reserved.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.  
Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

**Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!** Critical components<sup>1</sup>, may only be used in life-support devices or systems<sup>2</sup> with the express written approval of OSRAM OS.

<sup>1</sup> A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

<sup>2</sup> Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.